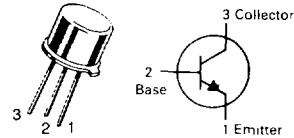


MAXIMUM RATINGS

| Rating | Symbol | MM3005 | MM3007 | Unit |
|---|----------------|-------------|--------|-------|
| Collector-Emitter Voltage | V_{CE0} | 60 | 100 | Vdc |
| Collector-Base Voltage | V_{CB0} | 80 | 120 | Vdc |
| Emitter-Base Voltage | V_{EBO} | 5.0 | | Vdc |
| Collector Current — Continuous | I_C | 2.5 | | Adc |
| Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C | P_D | 1.0 | | Watt |
| | | 5.71 | | mW/°C |
| Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C | P_D | 8.0 | | Watts |
| | | 45.6 | | mW/°C |
| Operating and Storage Junction Temperature Range | T_J, T_{stg} | -65 to +200 | | °C |

THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
|---|-----------------|-----|------|
| Thermal Resistance, Junction to Ambient | $R_{\theta JA}$ | 175 | °C/W |
| Thermal Resistance, Junction to Case | $R_{\theta JC}$ | 22 | °C/W |

**MM3005
MM3007**
**CASE 79-04, STYLE 1
TO-39 (TO-205AD)**

AUDIO TRANSISTORS
NPN SILICON
3
ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted.)

| Characteristic | Symbol | Min | Max | Unit |
|---|-------------------------------|----------------|-----------------|------|
| OFF CHARACTERISTICS | | | | |
| Collector-Emitter Breakdown Voltage(1) ($I_C = 10 \text{ mAdc}, I_E = 0$) | $V_{(BR)CEO}$ | 60 100 | — | Vdc |
| | MM3005 MM3007 | | | |
| Collector-Base Breakdown Voltage ($I_C = 100 \mu\text{Adc}, I_E = 0$) | $V_{(BR)CBO}$ | 80 120 | — | Vdc |
| | MM3005 MM3007 | | | |
| Emitter-Base Breakdown Voltage ($I_E = 100 \mu\text{Adc}, I_C = 0$) | $V_{(BR)EBO}$ | 5.0 | — | Vdc |
| Collector Cutoff Current ($V_{CB} = 60 \text{ Vdc}, I_E = 0$) ($V_{CB} = 100 \text{ Vdc}, I_E = 0$) | I_{CBO} | — — | 100 100 | nAdc |
| | MM3005 MM3007 | | | |
| Emitter Cutoff Current ($V_{EB} = 4.0 \text{ Vdc}, I_C = 0$) | I_{EBO} | — | 100 | nAdc |
| ON CHARACTERISTICS | | | | |
| DC Current Gain ($I_C = 1.0 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc}$) ($I_C = 150 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc}$)(1) ($I_C = 250 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc}$)(1) | h_{FE} | 40 50 50 | — 250 250 | — |
| | All Types MM3005 MM3007 | | | |
| Collector-Emitter Saturation Voltage(1) ($I_C = 150 \text{ mAdc}, I_E = 15 \text{ mAdc}$) | $V_{CE(sat)}$ | — | 0.35 | Vdc |
| Base-Emitter On Voltage(1) ($I_C = 150 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc}$) | $V_{BE(on)}$ | 0.60 | 0.75 | Vdc |
| SMALL-SIGNAL CHARACTERISTICS | | | | |
| Current-Gain — Bandwidth Product(1) ($I_C = 50 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f = 20 \text{ MHz}$) | f_T | 50 | — | MHz |
| Output Capacitance ($V_{CB} = 10 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MHz}$) | C_{obo} | — | 15 | pF |

 (1) Pulse Test: Pulse Width $\leq 300 \mu\text{s}$, Duty Cycle $\leq 2.0\%$.